

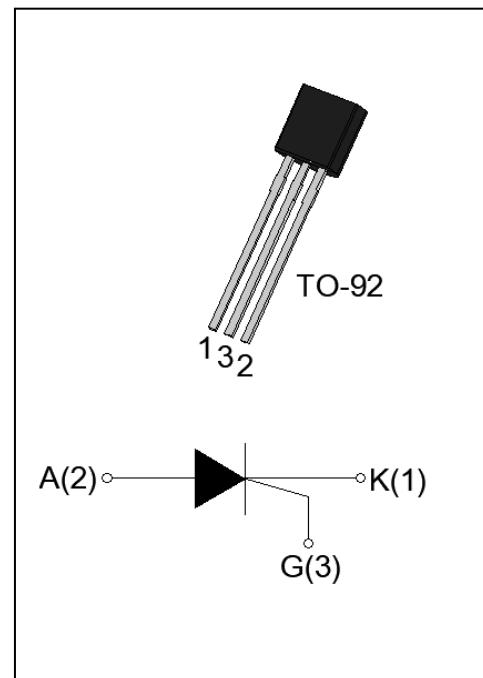


MCR100-8 1A Sensitive SCR

Rev.A.1.0

DESCRIPTION:

The MCR100-8 SCR provides high dV/dt rate with strong resistance to electromagnetic interface. It is especially recommended for use on residual current circuit breaker, straight hair, igniter etc. Complying with UL standards (File ref: E252906). Package TO-92 is RoHS compliant.



MAIN FEATURES

| Symbol | Value | Unit |
|---------------------|------------|---------|
| $I_{T(RMS)}$ | 1 | A |
| V_{DRM} / V_{RRM} | 800 | V |
| I_{GT} | ≤ 200 | μA |

ABSOLUTE MAXIMUM RATINGS

| Parameter | Symbol | Value | Unit |
|---|--------------|----------------------|-----------|
| Storage junction temperature range | T_{stg} | -40-150 | °C |
| Operating junction temperature range | T_j | -40-125 ^① | °C |
| Repetitive peak off-state voltage ($T_j=25^\circ C$) | V_{DRM} | 800 | V |
| Repetitive peak reverse voltage ($T_j=25^\circ C$) | V_{RRM} | 800 | V |
| Average on-state current ($T_c \leq 54^\circ C$) | $I_{T(AV)}$ | 0.6 | A |
| RMS on-state current ($T_c \leq 54^\circ C$) | $I_{T(RMS)}$ | 1 | A |
| Non repetitive surge peak on-state current ($t_p=10ms, T_j=25^\circ C$) | I_{TSM} | 12 | A |
| Non repetitive surge peak on-state current ($t_p=8.3ms, T_j=25^\circ C$) | | 13 | |
| I^2t value for fusing ($t_p=10ms, T_j=25^\circ C$) | I^2t | 0.72 | A^2s |
| Critical rate of rise of on-state current ($I_G=2 \times I_{GT}, f=100Hz, T_j=125^\circ C$) | dI/dt | 100 | $A/\mu s$ |
| Peak gate current ($t_p=20\mu s, T_j=125^\circ C$) | I_{GM} | 1 | A |

| | | | |
|--|--------------------|-----|----|
| Average gate power dissipation ($T_j=125^\circ\text{C}$) | $P_{G(\text{AV})}$ | 0.1 | W |
| Peak gate power | P_{GM} | 2 | W |
| Peak pulse voltage ($T_j=25^\circ\text{C}$; non-repetitive, off-state; FIG.7) | V_{pp} | 1 | kV |

NOTE 1: When we parallel connect a $\leq 1\text{K}\Omega$ resistor between Gate and Cathode, the T_j can reach 125°C ; if without this resistor, the T_j only can reach 110°C .

ELECTRICAL CHARACTERISTICS ($T_j=25^\circ\text{C}$ unless otherwise specified)

| Symbol | Test Condition | Value | | | Unit |
|-----------|--|-------|------|------|------------------|
| | | MIN. | TYP. | MAX. | |
| I_{GT} | $V_D=12\text{V}$ $R_L=33\Omega$ | - | 40 | 200 | μA |
| V_{GT} | | - | 0.6 | 0.8 | V |
| V_{GD} | $V_D=V_{DRM}$ $T_j=125^\circ\text{C}$ | 0.2 | - | - | V |
| I_L | $I_G=1.2 I_{GT}$ | - | - | 5 | mA |
| I_H | $I_T=0.05\text{A}$ | - | - | 4 | mA |
| dV/dt | $V_D=540\text{V}$ $T_j=125^\circ\text{C}$ $R_{GK}=1\text{K}\Omega$ | 200 | - | - | V/ μs |
| | $V_D=540\text{V}$ $T_j=125^\circ\text{C}$ $R_{GK}=220\Omega$ | 500 | - | - | |
| t_{on} | $I_G=10\text{mA}$ $I_A=20\text{mA}$ $I_R=2\text{mA}$ $T_j=25^\circ\text{C}$ | - | 2 | - | μs |
| t_{off} | | - | 50 | - | μs |

STATIC CHARACTERISTICS

| Symbol | Parameter | | Value(MAX.) | Unit |
|-----------|--------------------------------------|-------------------------|-------------|---------------|
| V_{TM} | $I_T=2\text{A}$ $t_p=380\mu\text{s}$ | $T_j=25^\circ\text{C}$ | 1.4 | V |
| V_{TO} | Threshold voltage | $T_j=125^\circ\text{C}$ | 0.8 | V |
| R_D | Dynamic Resistance | $T_j=125^\circ\text{C}$ | 0.1 | Ω |
| I_{DRM} | $V_D=V_{DRM}$ $V_R=V_{RRM}$ | $T_j=25^\circ\text{C}$ | 5 | μA |
| I_{RRM} | | $T_j=125^\circ\text{C}$ | 0.2 | mA |

THERMAL RESISTANCES

| Symbol | Parameter | Value | Unit |
|---------------|--------------------------|-------|---------------------------|
| $R_{th(j-c)}$ | junction to case (DC) | 61 | $^\circ\text{C}/\text{W}$ |
| $R_{th(j-a)}$ | junction to ambient (DC) | 130 | $^\circ\text{C}/\text{W}$ |

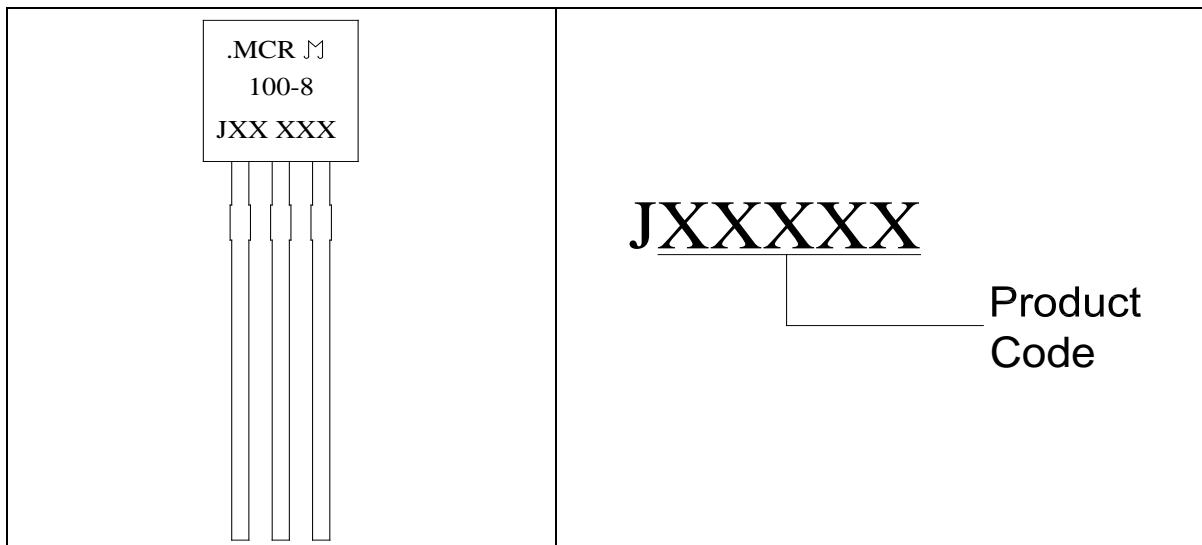
MARKING

FIG.1 Maximum power dissipation versus RMS on-state current

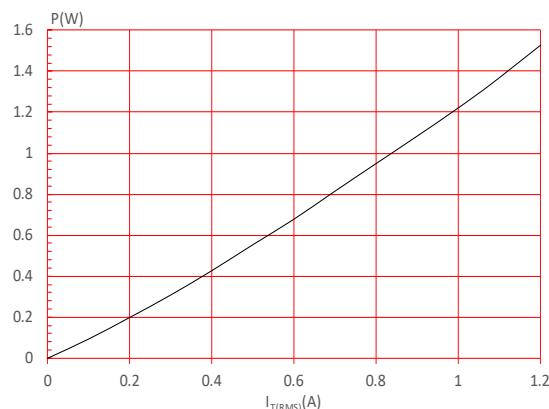


FIG.3: Surge peak on-state current versus number of cycles

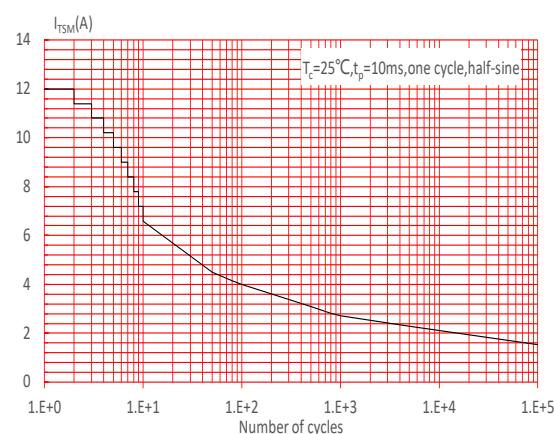


FIG.2: RMS on-state current versus case temperature

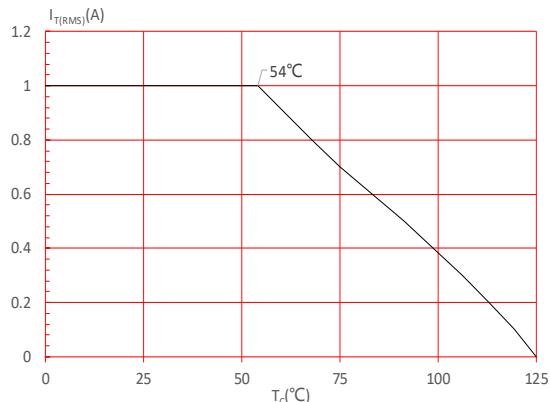


FIG.4: On-state characteristics

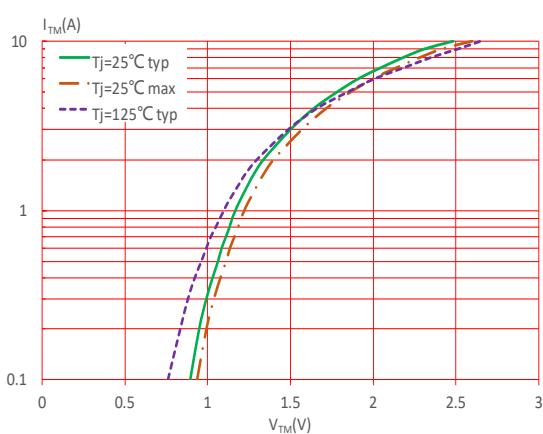




FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$, and corresponding value of I^2t ($dI/dt < 100\text{A}/\mu\text{s}$)

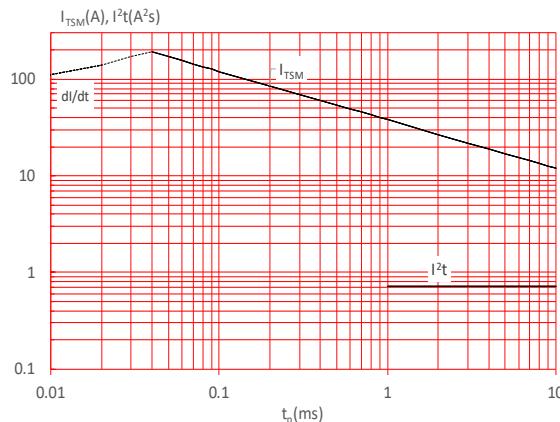


FIG.6: Relative variations of gate triggercurrent, holding current and latching current versus junction temperature

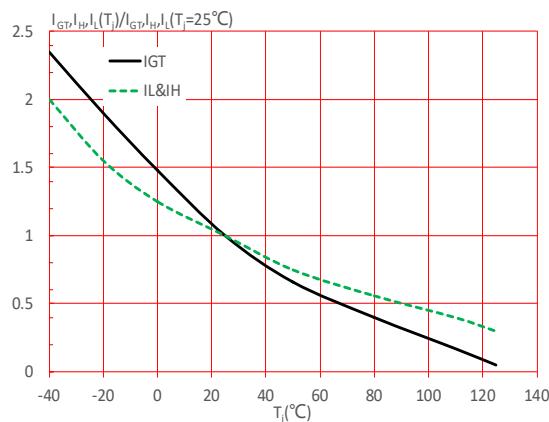
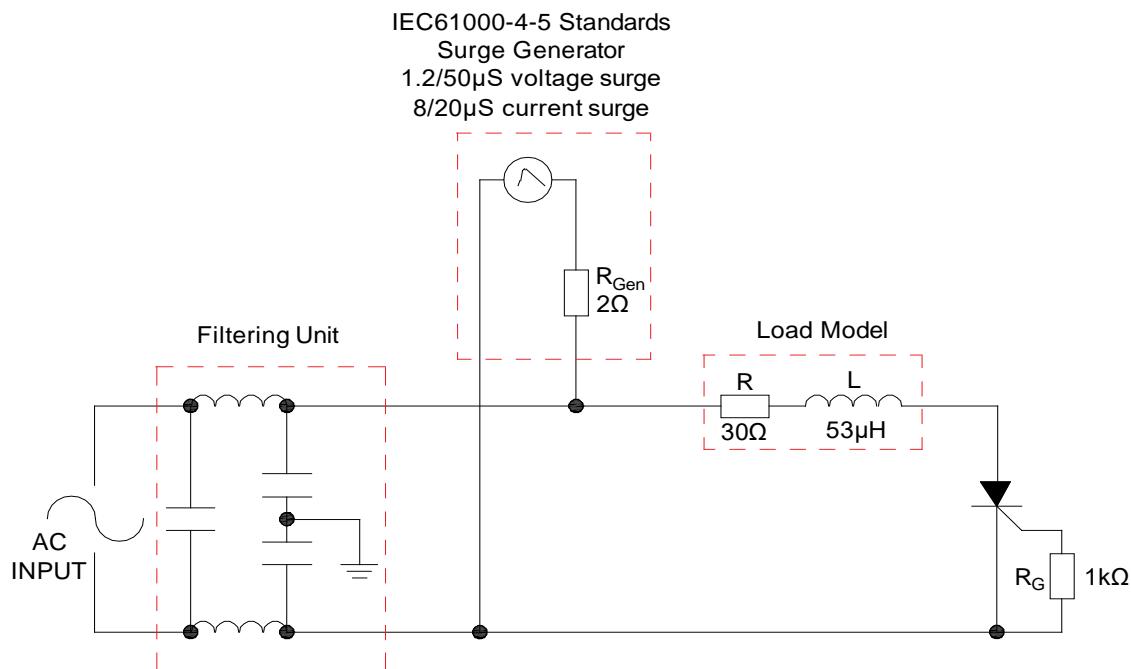


FIG.7: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards.



SHAPING AND SOLDERING PARAMETERS

Refer to 《Instructions for installation of plastic-sealed in-line power devices》 released by JieJie

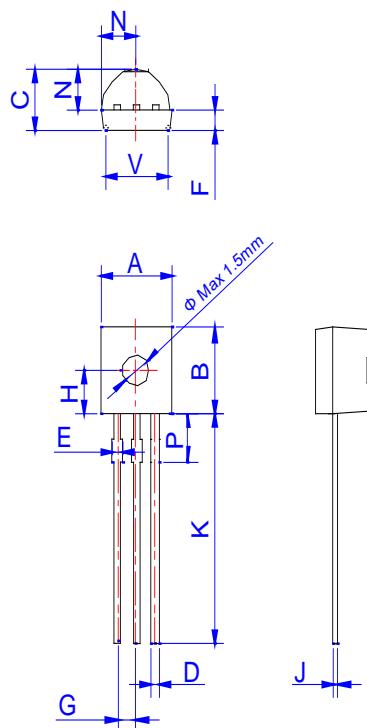
ORDERING INFORMATION

| Order code | Voltage V_{DRM}/V_{RRM} (V) | IGT(μA) | Package | Base qty. (pcs) | Delivery mode |
|-------------|----------------------------------|------------|---------|--------------------|---------------|
| MCR100-8 | 800 | ≤ 200 | TO-92 | 1,000 | Bulk Pack |
| MCR100-8-TR | | | | 2,000 | Tape & Reel |

Document Revision History

| Date | Revision | Changes |
|--------------|----------|-------------|
| Apr.12, 2023 | A.1.0 | Last update |

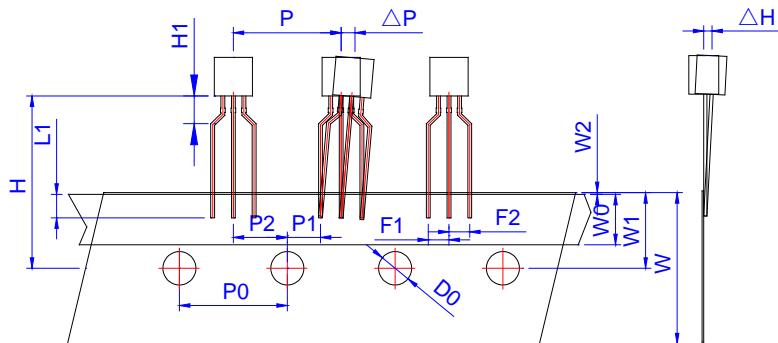
PACKAGE MECHANICAL DATA



| Ref. | Dimensions | | | | | |
|------|-------------|------|-------|--------|------|-------|
| | Millimeters | | | Inches | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 4.45 | | 5.20 | 0.175 | | 0.205 |
| B | 4.32 | | 5.33 | 0.170 | | 0.210 |
| C | 3.18 | | 4.19 | 0.125 | | 0.165 |
| D | 0.407 | | 0.533 | 0.016 | | 0.021 |
| E | 0.50 | | 0.70 | 0.020 | | 0.028 |
| F | 1.10 | | 1.30 | | | 0.051 |
| G | 1.10 | | 1.40 | 0.043 | | 0.055 |
| H | 2.20 | | 2.40 | 0.087 | | 0.094 |
| J | 0.36 | | 0.50 | 0.014 | | 0.020 |
| K | 12.70 | | 15.0 | 0.500 | | 0.591 |
| N | 2.04 | | 2.66 | 0.080 | | 0.105 |
| P | 1.80 | | 2.30 | 0.071 | | 0.091 |
| V | 4.10 | | 4.50 | 0.161 | | 0.177 |

DELIVERY MODE

| PACKAGE | OUTLINE | BAG (PCS) | INNER BOX (PCS) | CARTON BOX (PCS) |
|---------|-----------|--------------|--------------------|---------------------|
| TO-92 | Bulk Pack | 1,000 | 10,000 | 50,000 |



| Ref. | Dimensions | | | | | |
|------------|-------------|-------|-------|--------|-------|-------|
| | Millimeters | | | Inches | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| P | 12.40 | 12.70 | 13.00 | 0.488 | 0.500 | 0.512 |
| P0 | 12.40 | 12.70 | 13.00 | 0.488 | 0.500 | 0.512 |
| P1 | 3.55 | 3.85 | 4.15 | 0.140 | 0.152 | 0.163 |
| P2 | 5.95 | 6.35 | 6.75 | 0.233 | 0.250 | 0.265 |
| ΔP | -1.0 | 0 | 1.0 | -0.039 | 0 | 0.039 |
| F1、F2 | 2.30 | 2.50 | 2.70 | 0.090 | 0.098 | 0.106 |
| F1-F2 | -0.1 | 0 | 0.1 | -0.004 | 0 | 0.004 |
| W | 17.50 | 18.00 | 19.00 | 0.689 | 0.709 | 0.748 |
| W0 | 5.50 | 6.00 | 6.50 | 0.217 | 0.236 | 0.256 |
| W1 | 8.50 | 9.00 | 9.50 | 0.335 | 0.354 | 0.374 |
| W2 | | | 1.0 | | | 0.039 |
| D0 | 3.80 | 4.0 | 4.20 | 0.150 | 0.157 | 0.165 |
| ΔH | -1.0 | 0 | 1.0 | -0.039 | 0 | 0.039 |
| L1 | 2.5 | | | 0.098 | | |
| H | 18.0 | 19.0 | 20.0 | 0.709 | 0.748 | 0.787 |
| H1 | | | 2.70 | | | 0.106 |

| PACKAGE | OUTLINE | REEL (PCS) | INNER BOX (PCS) | CARTON BOX (PCS) |
|---------|-------------|---------------|--------------------|---------------------|
| TO-92 | Tape & Reel | / | 2,000 | 20,000 |



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